



Supplementary Materials

Graphene Templated DNA Arrays and Biotin-Streptavidin Sensitive Bio-Transistors Patterned by Dynamic Self-Assembly of Polymeric Films Confined within a Roll-on-Plate Geometry

Sangheon Jeon ^{1,†}, Jihye Lee ^{1,†}, Rowoon Park ^{1,†}, Jeonghwa Jeong ¹, Min Chan Shin ¹, Seong Un Eom ², Jinyoung Park ^{3,*}, and Suck Won Hong ^{1,*}

- ¹ Department of Cogno-Mechatronics Engineering, Department of Optics and Mechatronics Engineering, College of Nanoscience and Nanotechnology, Pusan National University, Busan 46241, Korea; sangheon.jn@gmail.com (S.J.); jihyelee970@gmail.com (J.L.);rowoon.p153@gmail.com (R.P.); 2jeong.s.o@gmail.com (J.J.); mch3024@gmail.com (M.C.S.)
- ² Substrate & Material Laboratory, LG Innotek Co., Ltd., Gumi 39419, Korea; sueom89@gmail.com
- ³ School of Applied Chemical Engineering, Kyungpook National University, Daegu 41566, Korea
- * Correspondence: jinpark@knu.ac.kr (J.P.); swhong@pusan.ac.kr (S.W.H.)
- + These authors contributed equally to this work.



Figure S1. The height profiles of the periodic PMMA stripes obtained from different concentration, $C = 0.5 \text{ mg mL}^{-1}$ (**a**) and 0.125 mg mL⁻¹ (**b**).



Figure S2. Close-up AFM images of GO-AuNPs stripe corresponding to the one portion of Figure 3e. The typical height of the GO-AuNPs stripe was ~30 nm.



Figure S3. Patterned arrays of GO/AuNPs by lift-off process of PMMA after the template-assisted deposition on the SiO₂/Si substrate. (**a**) Optical micrographs after the GO/AuNPs deposition on the patterned PMMA stripes with different concentrations of 0.5, 0.25, and 0.125 mg mL⁻¹. (**b**) After the removal of PMMA using an organic solvent. The scale bars are 10 μ m.





Figure S4. (a) Typical optical micrograph of micropatterned graphene channels on pair of Au/Cr electrodes, in which the back-gated multichannel GFET was built on the SiO₂/Si substrate. (b) AFM image and height profile of micropatterned graphene, measured from the marked area in (a). (c) A magnified SEM image shows the graphene conformably integrated on the electric pads after the oxygen plasma and the removal of PMMA etch masks.



Figure S5. (a) A photograph of the BioGFET integrated with a microfluidic system and the probing accesses. (b) A magnified view of the BioGFET as illustrated in Figure 6c.



Figure S6. Transfer characteristics after the PEI/PEG polymer coating on the graphene channels (black), and transfer characteristics after the biotinylation on the active channels in BioGFET (red).